

#### **Features**

- High input voltage (up to 50V)
- Low Power Consumption: 2µA (Typ)
- Maximum Output Current: 400mA
- Voltage drop:350mV@100mA(3.3V)
- Good Transient Response
- Output voltage accuracy: tolerance  $\pm 2\%$
- SOT89-3, SOT23-5 and SOT89-5 package
- PSRR:85dB@1KHz

#### **Applications**

- Portable, Battery Powered Equipmpm
- Microcontroller Applications
- Smoke detector and sensor
- Audio/Video equipment
- Weighting Scales
- Home Automation

### **General Description**

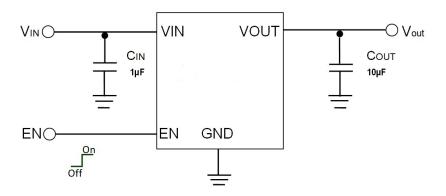
The HE2210 series is a high voltage, ultralow-power, low dropout voltage regulator. The device can deliver 400mA output current with a dropout voltage of 350mV and allows an input voltage as high as 50V. The typical quiescent current is only  $2\mu A$ . The device is available in fixed output voltages of 2.5,2.8,3.0,3.3,3.6 and 5.0V.The device features integrated short-circuit and thermal shutdown protection. Although designed primarily as fixed voltage regulators, the device can be used with external components to obtain variable voltages.

#### **Selection Table**

Part No.	Output Voltage	Package	Marking
HE2210M533R	3.3V	SOT23-5	AH-3C
HE2210M550R	5.0V	SOT23-5	AH-5J
HE2210P533R	3.3V	SOT89-5	АН33С
HE2210P550R	5.0V	SOT89-5	AH50C
HE2210PCxxR	XX	SOT89-3	AHXBX
HE2210PxxR	XX	SOT89-3	AH-XX

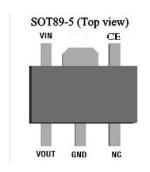
Note: "XX" stands for output voltages.

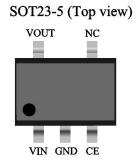
# **Application Circuits**

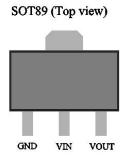




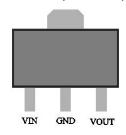
### **Pin Assignment**



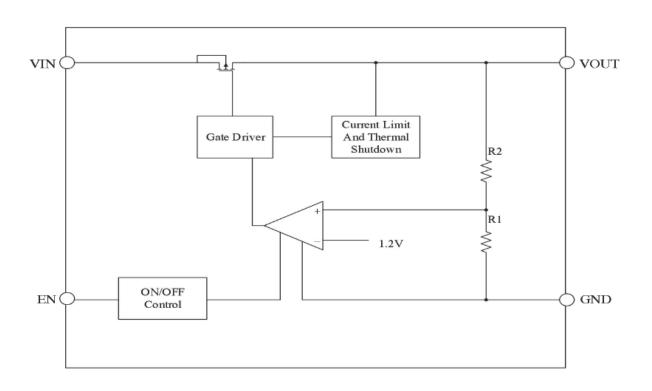




SOT89C(TOP view)



### **Functional Block Diagrara**





# Absolute Maximum Ratings (1)(2)

Paramete	er	Symbol	Maximum Rating	Unit
Input Volta			V	
Input Volta	ige	Vout V <sub>SS</sub> -0.3~V <sub>SS</sub> +6		V
Output Current		Іоит	400	mA
Power Dissipation	SOT23-5	Pd	400	mW
Fower Dissipation	SOT89	Fu Fu	500	IIIVV
Thermal Resistance	SOT23-5	R <sub>0JA</sub> <sup>(3)</sup>	250	°C/W
Thermal Resistance	SOT89	K <sub>θ</sub> JA **	200	°C/W
Operating Temp	oerature	Topr	-40~85	$^{\circ}$
Storage Temp	erature	Tstg	-40~125	$^{\circ}$
Soldering Temperature & Time		Tsolder	260℃, 10s	

Note (1): Exceeding these ratings may damage the device.

### **ESD Ratings**

Item	Description	Value	Unit
	Human Body Model (HBM)		
V(ESD-HBM)	ANSI/ESDA/JEDEC JS-001-2014	±4000	V
	Classification, Class: 2		
	Charged Device Mode (CDM)		
V(ESD-CDM)	ANSI/ESDA/JEDEC JS-002-2014	±200	V
	Classification, Class: C0b		
1	JEDEC STANDARD NO.78E APRIL 2016	1150	m A
ILATCH-UP	Temperature Classification, Class: I	±150	mA

ESD testing is performed according to the respective JESD22 JEDEC standard. The human body model is a 100 pF capacitor discharged through a  $1.5k\Omega$  resistor into each pin. The machine model is a 200pF capacitor discharged directly into each pin.

#### **Recommended Operating Conditions**

Parameter	MIN.	MAX.	Units
Supply voltage at V <sub>IN</sub>		30	V
Operating junction temperature range, Tj	-40	125	°C
Operating free air temperature range, TA	-40	85	°C

Note: All limits specified at room temperature (TA = 25°C) unless otherwise specified. All room temperature limits are 100% production tested. All limits at temperature extremes are ensured through correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).

Note (2): The device is not guaranteed to function outside of its operating conditions

Note (3): The package thermal impedance is calculated in accordance to JESD 51-7.



### **Electrical characteristics**

 $(At~T_A=25^{\circ}C,~C_{IN}=1uF,~V_{IN}=V_{OUTNOM}+1.0V,~C_{OUT}=10\mu F,~unless~otherwise~noted)$ 

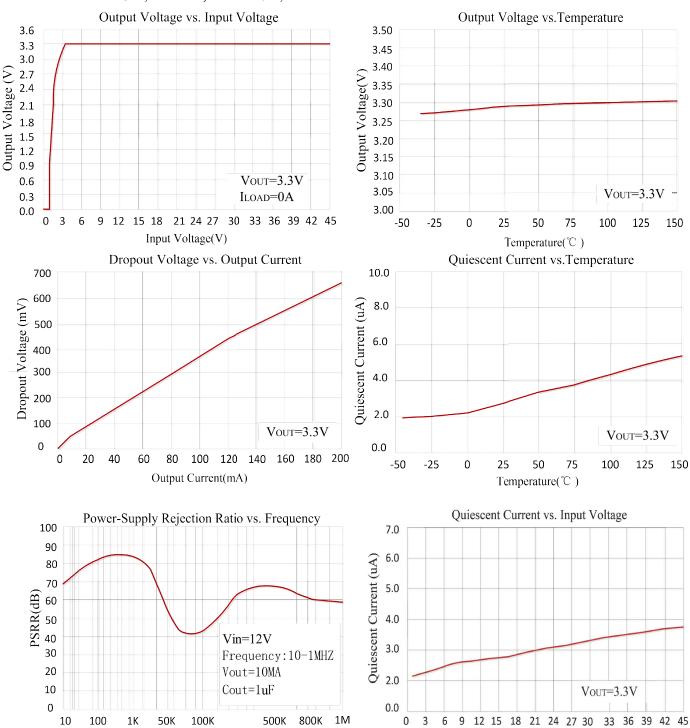
Symbol	Parameter	Test Conditions	Min	Тур.	Max	Units
V <sub>IN</sub>	Input Voltage		3.0		50	V
$I_Q$	Quiescent Current	V <sub>IN</sub> =12V No load	_	2.0	2.3	μΑ
V <sub>OUT</sub>	Output Voltage	$V_{IN}=12V$ $I_{OUT}=10mA$	-2.0		+2.0	%
$I_{SD}$	Shutdown Ground Current	$V_{IN}=0V$			0.1	μA
I <sub>LEAK</sub>	V <sub>OUT</sub> Shutdown Leakage Current	$V_{OUT} = 0V$	_	_	0.1	μА
I <sub>OUT_MAX</sub>	Output Current		_	400	_	mA
17	D (VI) (1)	$I_{OUT} = 10 \text{mA}$ $V_{IN} = V_{OUTNOM} - 0.1 V$	_	35	_	mV
$V_{DROP}$	Dropout Voltage(1)	$I_{OUT} = 100 \text{mA}$ $V_{IN} = V_{OUTNOM} - 0.1 \text{V}$	_	350	50 — mV	
ΔLOAD	Load Regulation	$V_{IN} = V_{OUT} + 1V$ $1 \text{mA} \leq I_{OUT} \leq 100 \text{mA}$	_	40		mV
ΔLINE	Line Regulation	$I_{OUT}=1 \text{mA},$ $V_{OUTNOM}+0.5 \text{V} \leq V_{IN} \leq 50 \text{V}$	_	0.01		%/V
PSRR	Power Supply Rejection Ratio	$V_{IN}$ =12V, $I_{OUT}$ =10mA f=1KHz, $V_{OUT}$ =3.3V	_	85		dB
V <sub>IH</sub>	EN Threshold Voltage,Logic-High	$V_{IN}$ =5.0V, $I_{OUT}$ =1mA	1.0	_	_	V
$V_{\rm IL}$	EN Threshold Voltage,Logic-Low	$V_{IN}=5.0V$		_	0.4	V
I <sub>LIMIT</sub>	Current Limit	$V_{IN} = V_{OUT} + 1V$	300	450		mA
I <sub>SHORT</sub>	Short /Start Load Current	RL=1Ω		100		mA
e <sub>NO</sub>	Output Noise Voltage	10Hz to 100kHz C <sub>OUT</sub> =1μF	_	100	_	μVRMS
$T_{SD}$	Thermal Shutdown Temperature		_	150		°C
$\Delta T_{SD}$	Thermal Shutdown Hysteresis		_	20	_	°C

Note: \*1 Dropout Voltage is the voltage difference between the input and the output at which the output voltage drops 2% below its nominal value.



## **Typical Performance Characteristics:**

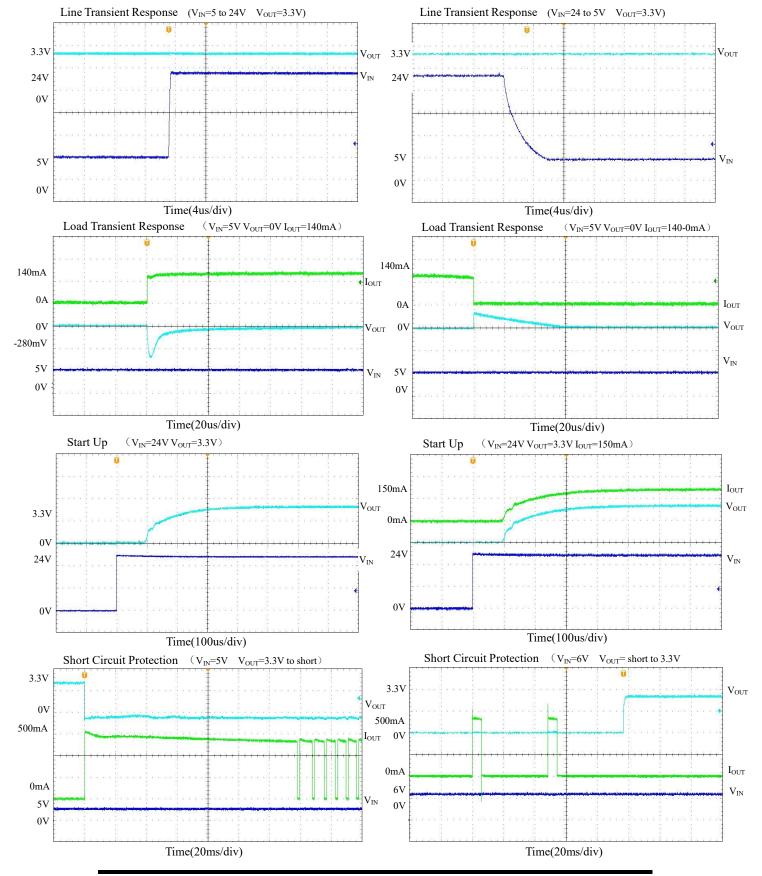
Test Condition: TA=25°C, Iout=1mA, COUT=10uF, unless otherwise noted



Input Voltage(V)

Frequency(Hz)







### **Application Guideline**

#### **Input Capacitor**

A  $10\mu F$  ceramic capacitor is recommended to connect between  $V_{DD}$  and GND pins to decouple input power supply glitch and noise. The amount of the capacitance may be increased without limit. This input capacitor must be located as close as possible to the device to assure input stability and less noise. For PCB layout, a wide copper trace is required for both VIN and GND.

#### **Output Capacitor**

An output capacitor is required for the stability of the LDO. The recommended output capacitance is 10µF, ceramic capacitor is recommended, and temperature characteristics are X7R or X5R. Higher capacitance values help to improve load/line transient response. The output capacitance may be increased to keep low undershoot/overshoot. Place output capacitor as close as possible to VOUT and GND pins.

#### **Dropout Voltage**

The dropout voltage refers to the voltage difference between the VIN and VOUT pins while operating at specific output current. The dropout voltage VDROP also can be expressed as the voltage drop on the pass-FET at specific output current (IRATED) while the pass-FET is fully operating at ohmic region and the pass-FET can be characterized as an resistance RDS(ON). Thus the dropout voltage can be defined as (VDROP = VIN - VOUT = RDS(ON) x IRATED). Fornormal operation, the suggested LDO operating range is (VIN > VOUT + VDROP) for good transient response and PSRR ability. Vice versa, while operating at the ohmic region will degrade the performance severely.

#### **Thermal Application**

For continuous operation, do not exceed the absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated as below: TA=25°C, PCB,

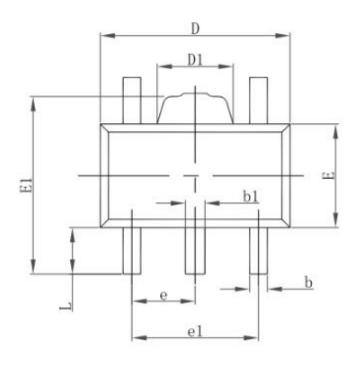
The max PD= (125°C - 25°C) / (Thermal Resistance °C/W)

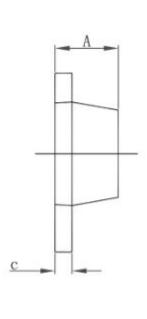
Power dissipation (PD) is equal to the product of the output current and the voltage drop across the output pass element, as shown in the equation below:

 $PD = (VIN - VOUT) \times IOUT$ 

# **Package Information**

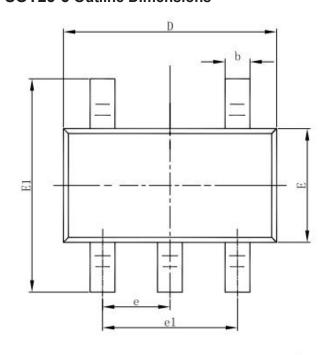
### **SOT89-5** Outline Dimensions

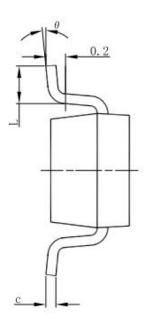


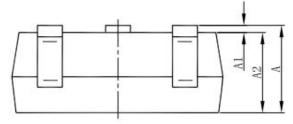


Combal	Dimensions In Millimeters		Dimensions In Inches	
Symbol	Min.	Max.	Min.	Max.
Α	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.360	0.560	0.014	0.022
С	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.400	1.800	0.055	0.071
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
е	1.500TYP.		0.060	TYP.
e1	2.900	3.100	0.114	0.122
L	0.900	1.100	0.035	0.043

### **SOT23-5** Outline Dimensions

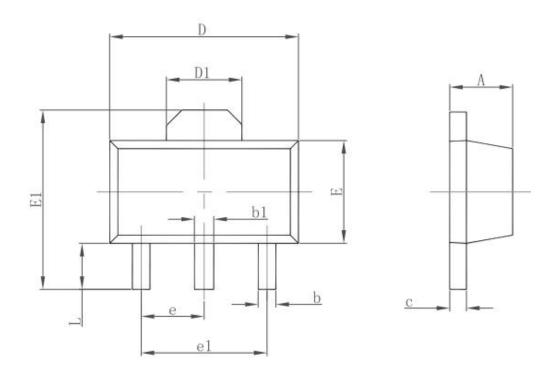






0 - 1 - 1	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	Min	Max	Min	Max
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
Е	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950(E	BSC)	0.037	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

### **3-pin SOT89 Outline Dimensions**



Symbol	Dimensions In Millimeters		Dimensions In Inches			
	Min.	Max.	Min.	Max.		
Α	1.400	1.600	0.055	0.063		
b	0.320	0.520	0.013	0.020		
b1	0.400	0.580	0.016	0.023		
С	0.350	0.440	0.014	0.017		
D	4.400	4.600	0.173	0.181		
D1	1.550	.550 REF. 0.061 REF.		1.550 REF.		REF.
E	2.300	2.600	0.091	0.102		
E1	3.940	4.250	0.155	0.167		
е	1.500 TYP.		0.060	TYP.		
e1	3.000	TYP.	P. 0.118 TYP.			
L	0.900	1.200	0.035	0.047		

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Linear Voltage Regulators category:

Click to view products by HEERMICR manufacturer:

Other Similar products are found below:

LV56831P-E LV5684PVD-XH MCDTSA6-2R L7815ACV-DG PQ3DZ53U LV56801P-E TLE42794G L78L05CZ/1SX L78LR05DL-MA-E 636416C 714954EB BA033LBSG2-TR LV5680P-E L78M15CV-DG L79M05T-E TLS202A1MBVHTSA1 L78LR05D-MA-E NCV317MBTG NTE7227 LV5680NPVC-XH LT1054CN8 MP2018GZD-5-Z MP2018GZD-33-Z MIC5281-3.3YMM MC78L06BP-AP TA48LS05F(TE85L,F) TA78L12F(TE12L,F) TC47BR5003ECT TCR2LN12,LF(S TCR2LN28,LF(S TCR2LN30,LF(S TCR3DF295,LM(CT TCR3DF40,LM(CT BA178M20CP-E2 L78M12ABDT LM7812SX/NOPB LR645N3-G-P003 LR645N3-G-P013 ZXTR2005P5-13 SCD7812BTG TCR3DF335,LM(CT ZXTR2012K-13 TLE42994E V33 ZXTR2008K-13 ZXTR2005K-13 L88R05DL-E ADP3300ARTZ-2.7RL7 LM120K-15/883 IFX54441LDVXUMA1 LM317D2T-TR